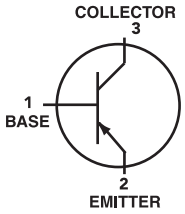
WEITRON

2SA1774

PNP General Purpose Transistors



SC-89
(SOT-523F)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	-50	Vdc
Collector-Base Voltage	V_{CBO}	-60	Vdc
Emitter-Base Voltage	V_{EBO}	-6.0	Vdc
Collector Current-Continuous	I_C	-150	mAdc

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (1) TA=25°C Derate above 25°C	P_D	150 1.2	mW mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage, Temperature	T_J ,Tstg	-55 to +150	°C

DEVICE MARKING

2SA1774Q=FQ, 2SA1774S=FS, 2SA1774R=FR

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (I_C= -1 uAdc, I_B=0)	$V_{(BR)CEO}$	-50	- -	Vdc
Collector-Base Breakdown Voltage (I_C= -50Adc, I_E=0)	$V_{(BR)CBO}$	-60	- -	Vdc
Emitter-Base Breakdown Voltage (I_E=-50 μAdc, I_C=0)	$V_{(BR)EBO}$	-6.0	- -	Vdc
Collector Cutoff Current (V_{CE}=-50 Vdc, I_E= 0)	I_{CEO}	-	-0.1	uAdc
Collector Cutoff Current (V_{CB}=-60 Vdc, I_E=0)	I_{CBO}	-	-0.1	uAdc
Emitter Cutoff Current (V_{EB}=-6.0Vdc, I_C=0)	I_{EBO}	-	-0.1	uAdc

1.FR-5=1.0 x 0.75 x 0.062 in

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted) (Countinued)

Characteristics	Symbol	Min	Typ	Max	Unit

ON CHARACTERISTICS

DC Current Gain (I_C=-1 mAdc, V_{CE}=-6.0 Vdc)	h_{FE}	120	-	560	-
Collector-Emitter Saturation Voltage (I_C=-50 mAdc, I_B=-5mAdc)	$V_{CE(sat)}$	-	-	-0.5	Vdc
Output Capacitance (V_{CB}=-12Vdc, I_E=0A, f=1MHZ)	Cob	-	4.0	5.0	PF
Current-Gain-Bandwidth Product (I_E=2 mAdc, V_{CE}=-12 Vdc,f=30 MHZ)	f_T	-	140	-	MHz

CLASSIFICATION OF h_{FE}

Item	Q	R	S
Range	120-270	180-390	270-560
Marking	FQ	FR	FS

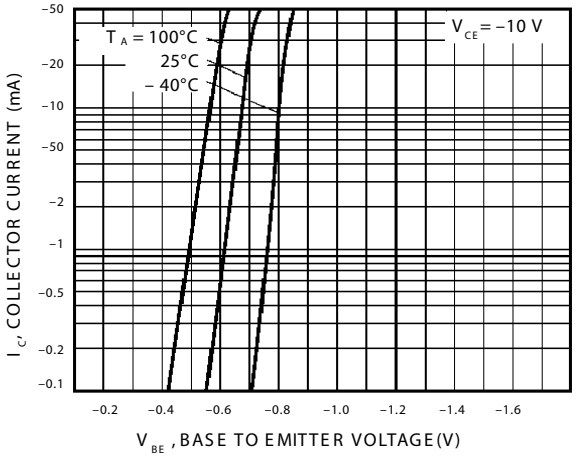


FIG.1 Grounded emitter propagation characteristics

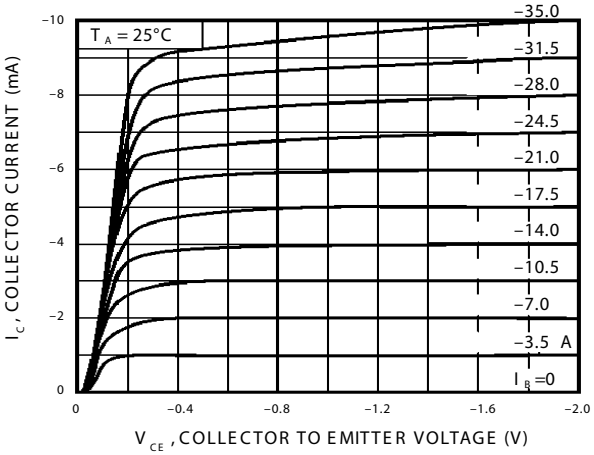


FIG.2 Grounded emitter output characteristics(Ⅰ)

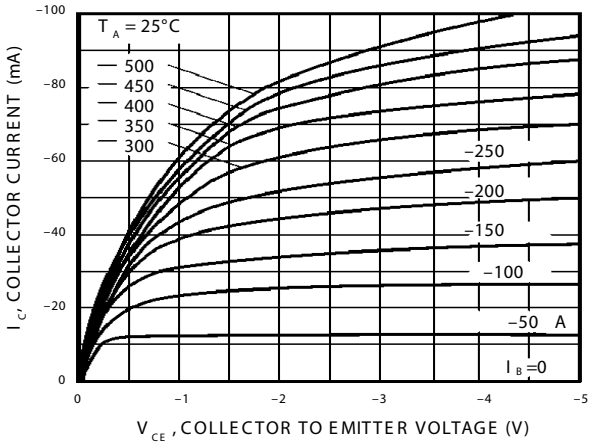


FIG.3 Grounded emitter output characteristics(Ⅱ)

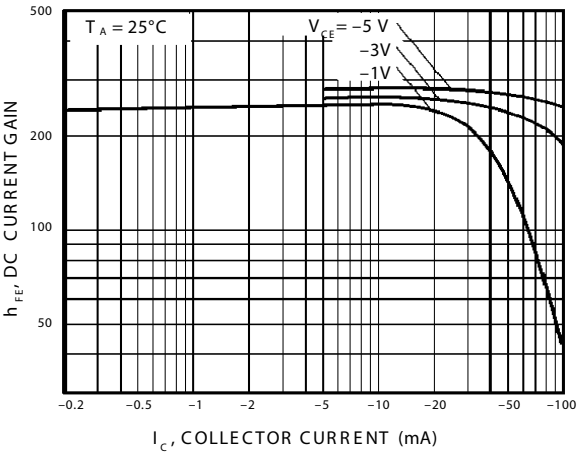


FIG.4 DC current gain vs. collector current (Ⅰ)

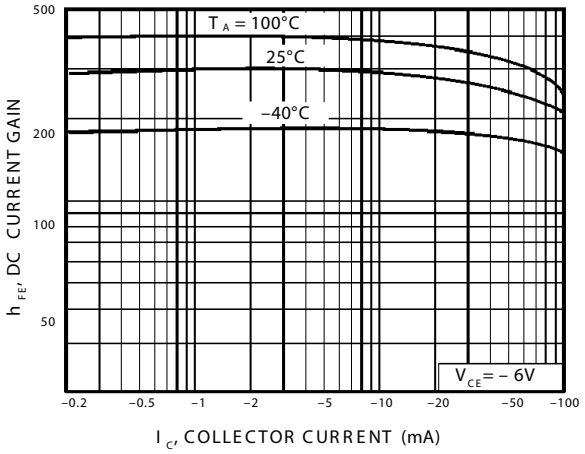


FIG.5 DC current gain vs. collector current (Ⅱ)

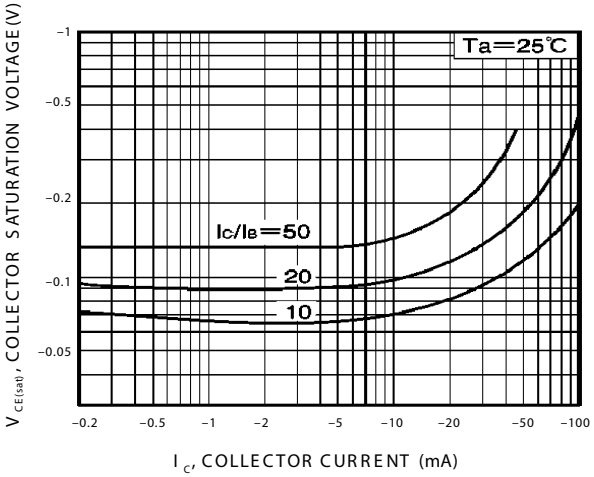


FIG.6 Collector-emitter saturation voltage vs. collector current (Ⅰ)

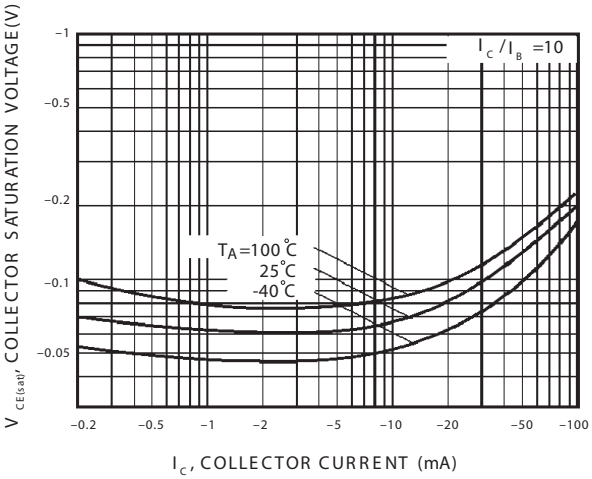


FIG.7 Collector-emitter saturation voltage vs. collector current (Ⅱ)

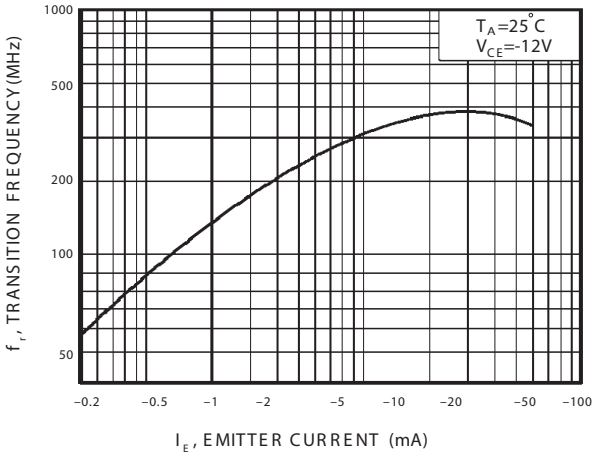


FIG.8 Gain bandwidth product vs. emitter current

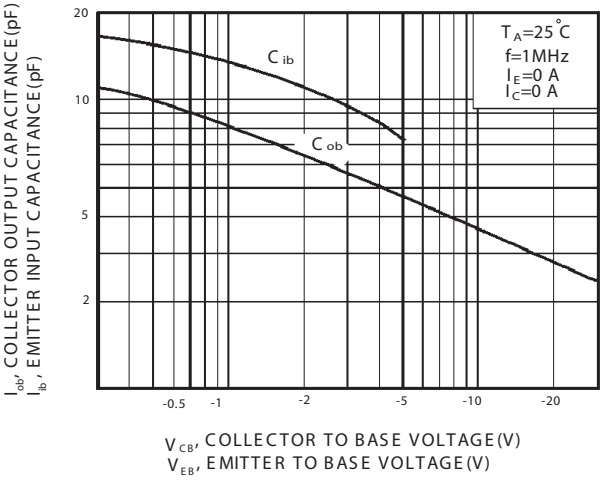
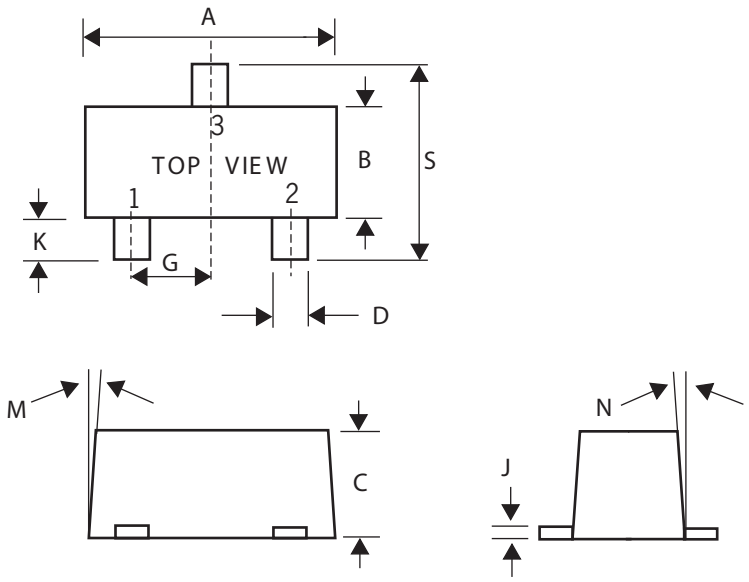


FIG.9 Collector output capacitance vs.collector-base voltage Emitter inputcapacitance vs. emitter-base voltage

SC-89 Outline Demensions

Unit:mm



SC-89			
Dim	**Min**	**Nom**	**Max**
A	1.50	1.60	1.70
B	0.75	0.85	0.95
C	0.60	0.70	0.80
D	0.23	0.28	0.33
G		0.50BSC	
J	0.10	0.15	0.20
K	0.30	0.40	0.50
M	---	---	10°
N	---	---	10°
S	1.50	1.60	1.70